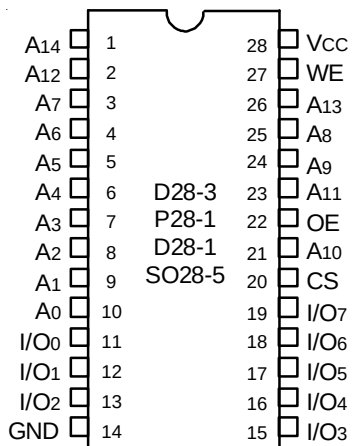


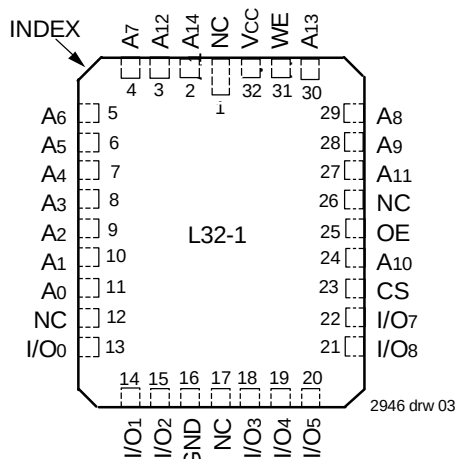


Pin Configurations



2946 drw 02

DIP/SOJ Top View



2946 drw 03

32-Pin LCC Top View

Pin Descriptions

Name	Description
A0 - A14	Address Inputs
I/O0 - I/O7	Data Input/Output
$\overline{CS}$	Chip Select
$\overline{WE}$	Write Enable
$\overline{OE}$	Output Enable
GND	Ground
Vcc	Power

2946 tbl 01

Truth Table⁽¹⁾

$\overline{WE}$	$\overline{CS}$	$\overline{OE}$	I/O	Function
X	H	X	High-Z	Standby (ISB)
X	V _{HC}	X	High-Z	Standby (ISB1)
H	L	H	High-Z	Output Disabled
H	L	L	DOUT	Read Data
L	L	X	DIN	Write Data

2946 tbl 02

NOTE:

1. H = V_{IH}, L = V_{IL}, X = Don't care.

Absolute Maximum Ratings⁽¹⁾

Symbol	Rating	Com'l.	Ind.	Mil.	Unit
V _{TERM}	Terminal Voltage with Respect to GND	-0.5 to +7.0	-0.5 to +7.0	-0.5 to +7.0	V
T _A	Operating Temperature	0 to +70	-40 to +85	-55 to +125	°C
T _{BIAS}	Temperature Under Bias	-55 to +125	-55 to +125	-65 to +135	°C
T _{STG}	Storage Temperature	-55 to +125	-55 to +125	-65 to +150	°C
P _T	Power Dissipation	1.0	1.0	1.0	W
I _{OUT}	DC Output Current	50	50	50	mA

2946 tbl 03

NOTE:

1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Capacitance (T_A = +25°C, f = 1.0MHz)

Symbol	Parameter ⁽¹⁾	Conditions	Max.	Unit
C _{IN}	Input Capacitance	V _{IN} = 0V	11	pF
C _{VO}	I/O Capacitance	V _{OUT} = 0V	11	pF

2946 tbl 04

NOTE:

1. This parameter is determined by device characterization, but is not production tested.

Recommended Operating Temperature and Supply Voltage

Grade	Temperature	GND	Vcc
Military	-55°C to +125°C	0V	5V ± 10%
Industrial	-40°C to +85°C	0V	5V ± 10%
Commercial	0°C to +70°C	0V	5V ± 10%

2946 tbl 05

Recommended DC Operating Conditions

Symbol	Parameter	Min.	Typ.	Max.	Unit
Vcc	Supply Voltage	4.5	5.0	5.5	V
GND	Ground	0	0	0	V
V _{IH}	Input High Voltage	2.2	—	6.0	V
V _{IL}	Input Low Voltage	-0.5 ⁽¹⁾	—	0.8	V

2946 tbl 06

NOTE:

- V_{IL} (min.) = -3.0V for pulse width less than 20ns, once per cycle.

DC Electrical Characteristics^(1,2) (Vcc = 5.0V ± 10%, VLc = 0.2V, VHC = Vcc - 0.2V)

Symbol	Parameter	Power	71256S/L20		71256S/L25		71256S/L35		71256S/L45		Unit
			Com'l.	Mil.	Com'l. & Ind	Mil.	Com'l. & Ind	Mil.	Com'l.	Mil.	
ICC	Dynamic Operating Current CS ≤ V _{IL} , Outputs Open Vcc = Max., f _{MAX} ⁽²⁾	S	—	—	—	150	—	140	—	135	mA
		L	135	—	115	130	105	120	—	115	
ISB	Standby Power Supply Current (TTL Level), CS ≥ V _{IH} , Vcc = Max., Outputs Open, f = f _{MAX} ⁽²⁾	S	—	—	—	20	—	20	—	20	mA
		L	3	—	3	3	3	3	—	3	
ISB1	Full Standby Power Supply Current (CMOS Level), CS ≥ V _{HC} , Vcc = Max., f = 0	S	—	—	—	20	—	20	—	20	mA
		L	0.4	—	0.4	1.5	0.4	1.5	—	1.5	

2946 tbl 07

Symbol	Parameter	Power	71256S/L55	71256S/L70	71256S/L85	71256S/L100	Unit
			Mil.	Mil.	Mil.	Mil.	
ICC	Dynamic Operating Current CS ≤ V _{IL} , Outputs Open Vcc = Max., f _{MAX} ⁽²⁾	S	135	135	135	135	mA
		L	115	115	115	115	
ISB	Standby Power Supply Current (TTL Level), CS ≥ V _{IH} , Vcc = Max., Outputs Open, f = f _{MAX} ⁽²⁾	S	20	20	20	20	mA
		L	3	3	3	3	
ISB1	Full Standby Power Supply Current (CMOS Level), CS ≥ V _{HC} , Vcc = Max., f = 0	S	20	20	20	20	mA
		L	1.5	1.5	1.5	1.5	

2946 tbl 08

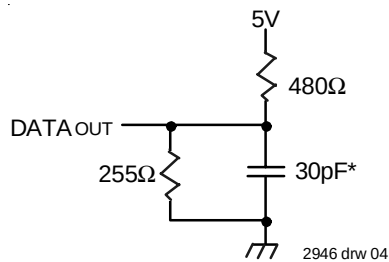
NOTES:

- All values are maximum guaranteed values.
- f_{MAX} = 1/TRC, all address inputs are cycling at f_{MAX}; f = 0 means no address pins are cycling.

AC Test Conditions

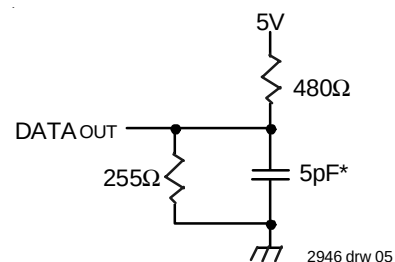
Input Pulse Levels	GND to 3.0V
Input Rise/Fall Times	5ns
Input Timing Reference Levels	1.5V
Output Reference Levels	1.5V
AC Test Load	See Figures 1 and 2

2946 tbl 09



2946 drw 04

Figure 1. AC Test Load



2946 drw 05

Figure 2. AC Test Load

(for tCLZ, tOLZ, tCHZ, tOHZ, tOW, and tWHZ)

*Includes scope and jig capacitances

DC Electrical Characteristics (V_{CC} = 5.0V ± 10%)

Symbol	Parameter	Test Conditions		IDT71256S			IDT71256L			Unit
				Min.	Typ.	Max.	Min.	Typ.	Max.	
I _{LI}	Input Leakage Current	V _{CC} = Max., V _{IN} = GND to V _{CC}	MIL. COM"L & IND.	— —	— —	10 5	— —	— —	5 2	μA
I _{LO}	Output Leakage Current	V _{CC} = Max., $\overline{\text{CS}}$ = V _H , V _{OUT} = GND to V _{CC}	MIL. COM"L & IND.	— —	— —	10 5	— —	— —	5 2	μA
V _{OL}	Output Low Voltage	I _{OL} = 8mA, V _{CC} = Min.		—	—	0.4	—	—	0.4	V
		I _{OL} = 10mA, V _{CC} = Min.		—	—	0.5	—	—	0.5	
V _{OH}	Output High Voltage	I _{OH} = -4mA, V _{CC} = Min.		2.4	—	—	2.4	—	—	V

2946 tbl 10

Data Retention Characteristics Over All Temperature Ranges

(L Version Only) (V_{LC} = 0.2V, V_{HC} = V_{CC} - 0.2V)

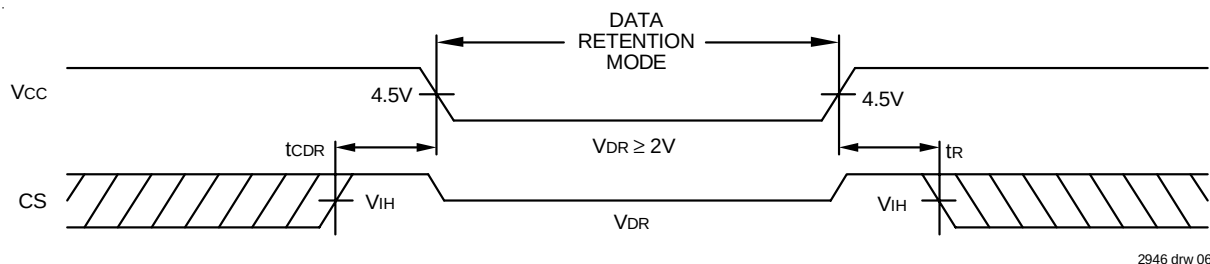
Symbol	Parameter	Test Condition	Min.	Typ. ⁽¹⁾ V _{CC} @		Max. V _{CC} @		Unit
				2.0V	3.0V	2.0V	3.0V	
V _{DR}	V _{CC} for Data Retention	—	2.0	—	—	—	—	V
I _{CDR}	Data Retention Current	MIL. COM"L. & IND.	— —	— —	— —	500 120	800 200	μA
t _{CDR}	Chip Deselect to Data Retention Time	$\overline{\text{CS}} \geq V_{HC}$	0	—	—	—	—	ns
t _{tr} ⁽³⁾	Operation Recovery Time		t _{RC} ⁽²⁾	—	—	—	—	ns

2946 tbl 11

NOTES:

- T_A = +25°C.
- t_{RC} = Read Cycle Time.
- This parameter is guaranteed by device characterization, but is not production tested.

Low Vcc Data Retention Waveform



2946 drw 06

AC Electrical Characteristics (Vcc = 5.0V ± 10%, All Temperature Ranges)

Symbol	Parameter	71256L20 ⁽¹⁾		71256S25 71256L25		71256S35 71256L35		71256S45 ⁽³⁾ 71256L45 ⁽³⁾		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
Read Cycle										
t _{RC}	Read Cycle Time	20	—	25	—	35	—	45	—	ns
t _{AA}	Address Access Time	—	20	—	25	—	35	—	45	ns
t _{ACS}	Chip Select Access Time	—	20	—	25	—	35	—	45	ns
t _{CLZ} ⁽²⁾	Chip Select to Output in Low-Z	5	—	5	—	5	—	5	—	ns
t _{CHZ} ⁽²⁾	Chip Deselect to Output in High-Z	—	10	—	11	—	15	—	20	ns
t _{OE}	Output Enable to Output Valid	—	10	—	11	—	15	—	20	ns
t _{OLZ} ⁽²⁾	Output Enable to Output in Low-Z	2	—	2	—	2	—	0	—	ns
t _{OHZ} ⁽²⁾	Output Disable to Output in High-Z	2	8	2	10	2	15	—	20	ns
t _{OH}	Output Hold from Address Change	5	—	5	—	5	—	5	—	ns
Write Cycle										
t _{WC}	Write Cycle Time	20	—	25	—	35	—	45	—	ns
t _{CW}	Chip Select to End-of-Write	15	—	20	—	30	—	40	—	ns
t _{AW}	Address Valid to End-of-Write	15	—	20	—	30	—	40	—	ns
t _{AS}	Address Set-up Time	0	—	0	—	0	—	0	—	ns
t _{WP}	Write Pulse Width	15	—	20	—	30	—	35	—	ns
t _{WR}	Write Recovery Time	0	—	0	—	0	—	0	—	ns
t _{DW}	Data to Write Time Overlap	11	—	13	—	15	—	20	—	ns
t _{WHZ} ⁽²⁾	Write Enable to Output in High-Z	—	10	—	11	—	15	—	20	ns
t _{DH}	Data Hold from Write Time	0	—	0	—	0	—	0	—	ns
t _{OW} ⁽²⁾	Output Active from End-of-Write	5	—	5	—	5	—	5	—	ns

2946 tbl 12

NOTES:

- 0° to +70°C temperature range only.
- This parameter is guaranteed by device characterization, but is not production tested.
- 55°C to +125°C temperature range only.

AC Electrical Characteristics (V_{CC} = 5.0V ± 10%, Military Temperature Ranges)

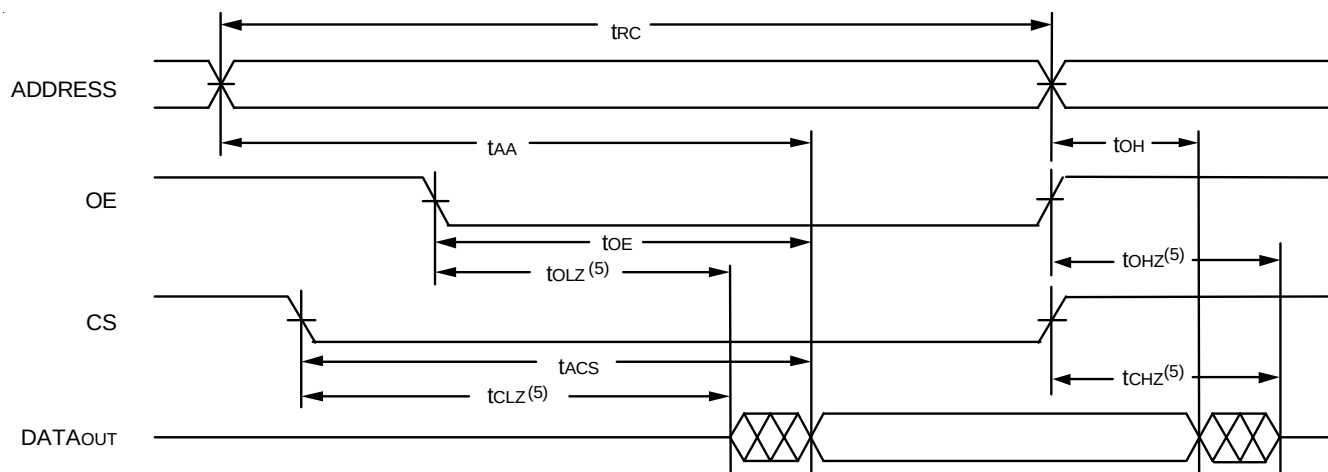
Symbol	Parameter	71256S55 ⁽¹⁾ 71256L55 ⁽¹⁾		71256S70 ⁽¹⁾ 71256L70 ⁽¹⁾		71256S85 ⁽¹⁾ 71256L85 ⁽¹⁾		71256S100 ⁽¹⁾ 71256L100 ⁽¹⁾		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
Read Cycle										
tRC	Read Cycle Time	55	—	70	—	85	—	100	—	ns
tAA	Address Access Time	—	55	—	70	—	85	—	100	ns
tACS	Chip Select Access Time	—	55	—	70	—	85	—	100	ns
tOLZ ⁽²⁾	Chip Select to Output in Low-Z	5	—	5	—	5	—	5	—	ns
tCHZ ⁽²⁾	Chip Deselect to Output in High-Z	—	25	—	30	—	35	—	40	ns
tOE	Output Enable to Output Valid	—	25	—	30	—	35	—	40	ns
tOLZ ⁽²⁾	Output Enable to Output in Low-Z	0	—	0	—	0	—	0	—	ns
tOHZ ⁽²⁾	Output Disable to Output in High-Z	0	25	0	30	—	35	—	40	ns
tOH	Output Hold from Address Change	5	—	5	—	5	—	5	—	ns
Write Cycle										
tWC	Write Cycle Time	55	—	70	—	85	—	100	—	ns
tCW	Chip Select to End-of-Write	50	—	60	—	70	—	80	—	ns
tAW	Address Valid to End-of-Write	50	—	60	—	70	—	80	—	ns
tAS	Address Set-up Time	0	—	0	—	0	—	0	—	ns
tWP	Write Pulse Width	40	—	45	—	50	—	55	—	ns
tWR	Write Recovery Time	0	—	0	—	0	—	0	—	ns
tDW	Data to Write Time Overlap	25	—	30	—	35	—	40	—	ns
tWHZ ⁽²⁾	Write Enable to Output in High-Z	—	25	—	30	—	35	—	40	ns
tDH	Data Hold from Write Time ($\overline{WE}$)	0	—	0	—	0	—	0	—	ns
tOW ⁽²⁾	Output Active from End-of-Write	5	—	5	—	5	—	5	—	ns

2946 tbl 13

NOTES:

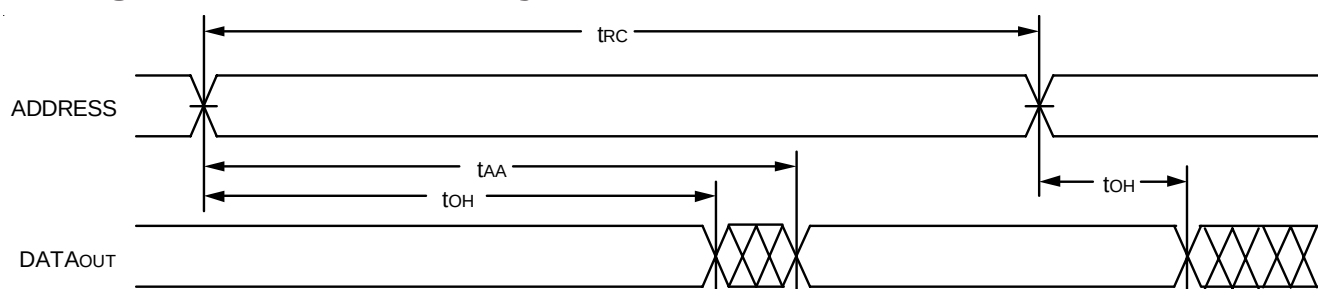
- 55° to +125°C temperature range only.
- This parameter is guaranteed by device characterization, but is not production tested.

Timing Waveform of Read Cycle No. 1⁽¹⁾



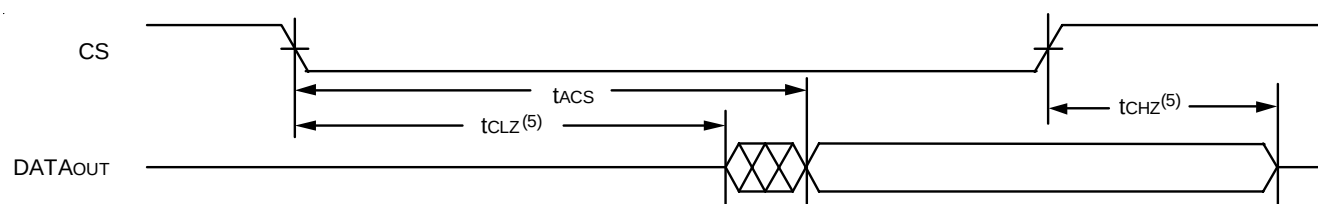
2946 drw 07

Timing Waveform of Read Cycle No. 2^(1,2,4)



2946 drw 08

Timing Waveform of Read Cycle No. 2^(1,3,4)

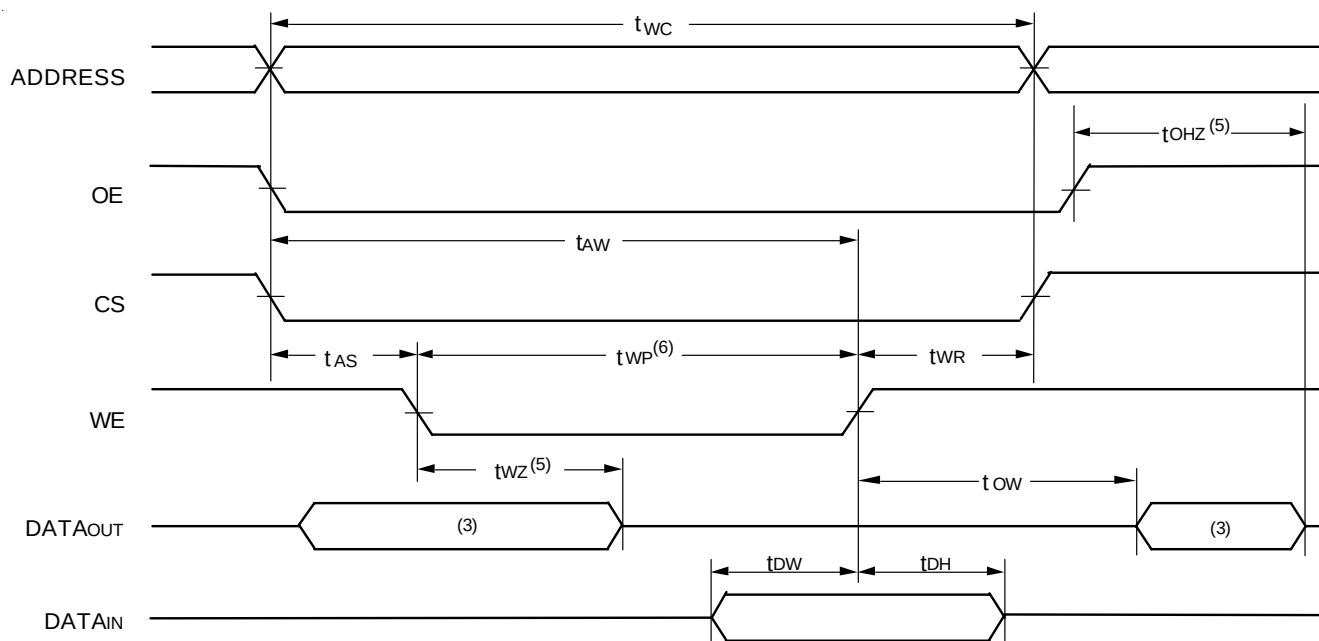


2946 drw 09

NOTES:

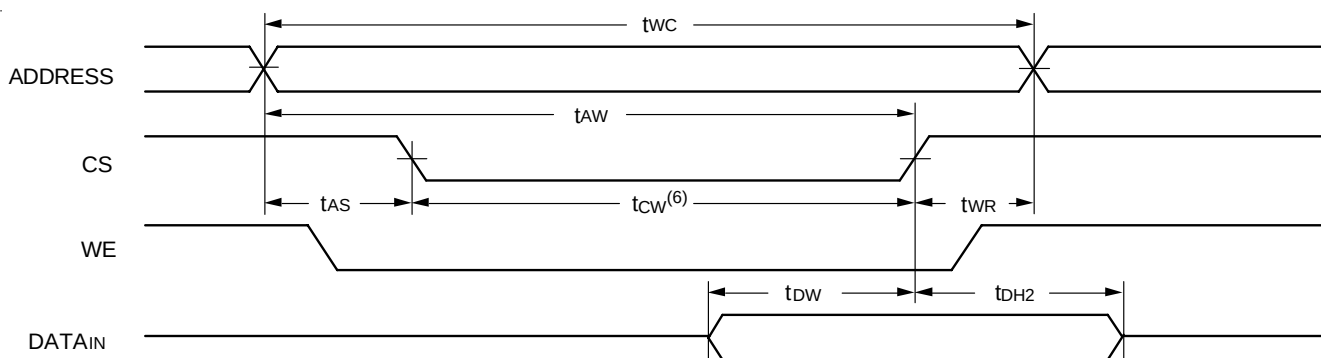
1. $\overline{WE}$ is HIGH for Read Cycle.
2. Device is continuously selected, $\overline{CS}$ is LOW.
3. Address valid prior to or coincident with $\overline{CS}$ transition LOW.
4. $\overline{OE}$ is LOW.
5. Transition is measured $\pm 200\text{mV}$ from steady state.

Timing Waveform of Write Cycle No. 1 ($\overline{WE}$ Controlled Timing)^(1,2,4,6)



2946 drw 10

Timing Waveform of Write Cycle No. 2 ($\overline{CS}$ Controlled Timing)^(1,2,4)

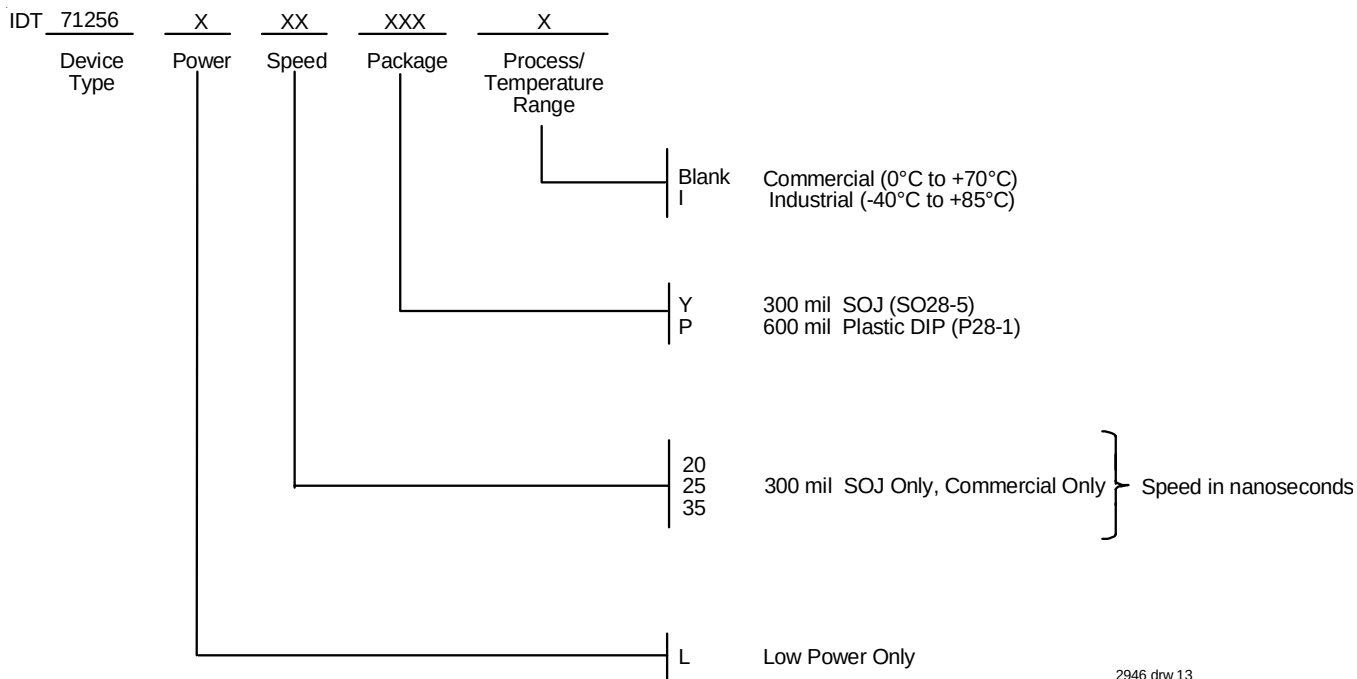


2946 drw 11

NOTES:

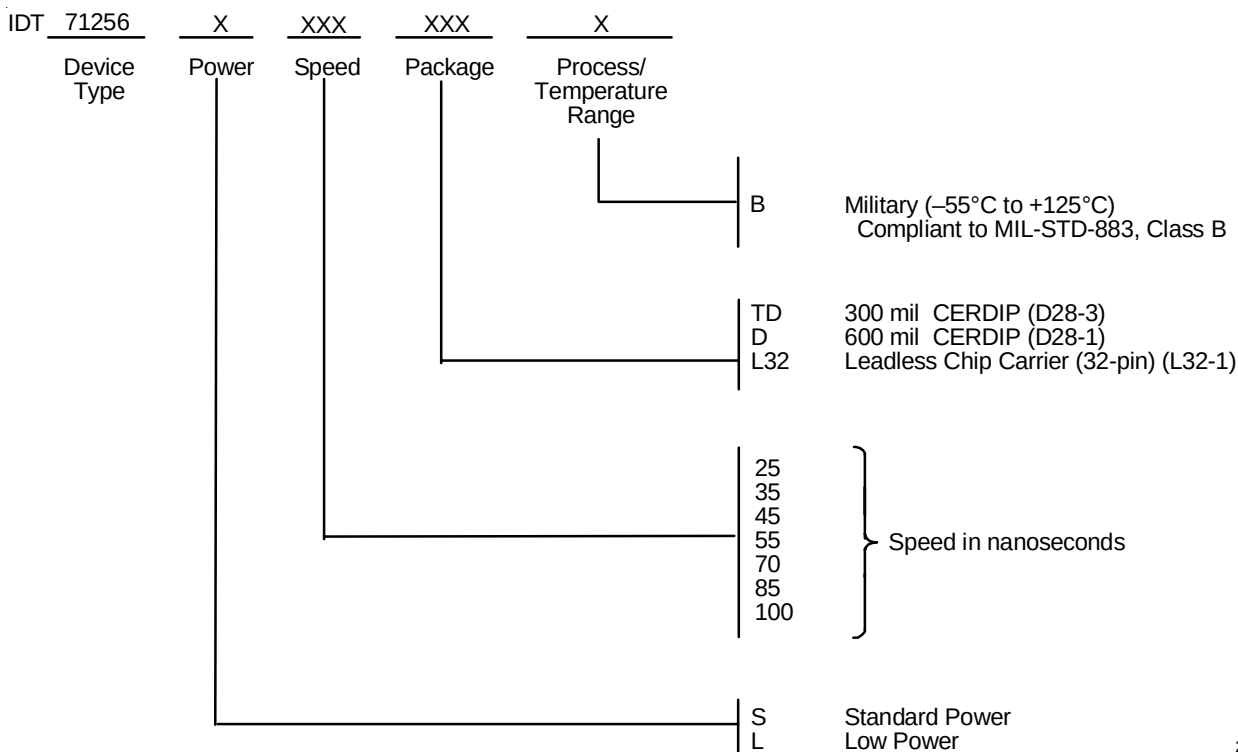
1. A write occurs during the overlap of a LOW $\overline{CS}$ and a LOW $\overline{WE}$.
2. t_{WR} is measured from the earlier of $\overline{CS}$ or $\overline{WE}$ going HIGH to the end of the write cycle.
3. During this period, I/O pins are in the output state so that the input signals must not be applied.
4. If the $\overline{CS}$ LOW transition occurs simultaneously with or after the $\overline{WE}$ LOW transition, the outputs remain in a high-impedance state.
5. Transition is measured $\pm 200\text{mV}$ from steady state.
6. If $\overline{OE}$ is LOW during a $\overline{WE}$ controlled write cycle, the write pulse width must be the larger of t_{WP} or $(t_{WHZ} + t_{DW})$ to allow the I/O drivers to turn off and data to be placed on the bus for the required t_{DW} . If $\overline{OE}$ is HIGH during a $\overline{WE}$ controlled write cycle, this requirement does not apply and the minimum write pulse width can be as short as the specified t_{WP} . For a $\overline{CS}$ controlled write cycle, $\overline{OE}$ may be LOW with no degradation to t_{CW} .

Ordering Information — Commercial & Industrial



2946 drw 13

Ordering Information — Military



2946 drw 12

Datasheet Document History

11/4/99		Updated to new format
	Pp. 1–5, 9	Added Industrial Temperature Range offerings
	Pg. 1	Removed 30, 120, and 150ns military and 45ns commercial speed grade offerings.
	Pg. 2	Removed P28-2 package from DIP/SOJ Top View
	Pg. 3	Removed 30ns and 45ns (Commercial only) speed grade offerings from DC Electrical table
		Revised notes and footnotes
	Pg. 5	Removed 30ns speed grade offering from AC Electrical table
		Revised notes and footnotes
	Pg. 6	Expressed Military Temperature range on AC Electrical table
		Revised notes and footnotes
	Pg. 8	Removed Note 1 and renumbered notes and footnotes
	Pg. 9	Revised Ordering Information and presented by temperature range offering
	Pg. 10	Added Datasheet Document History
08/09/00		Not recommended for new designs
02/01/01		Remove "Not recommended for new designs"



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